

L Number	Hits	Search Text	DB	Time stamp
1	2522	nanotube.ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 13:56
2	2522	nanotube.ti.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 13:56
3	193	nanotube.ti.	USPAT	2004/11/08 13:56
4	413	(977/DIG.1).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 14:06
5	3371	((438/142) or (438/159) or (438/778) or (438/780) or (257/213)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/08 14:08
-	58731	nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:16
-	3255829	metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:34
-	1939545	semiconductor or silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:14
-	279	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near metal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:01
-	170	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 21:53
-	20	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near met	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:35
-	26	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near sem	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:35
-	55	((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near metal) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near met)) and (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (semiconductor or silicon)) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near sem))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:35

-	50	(((((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near metal) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near met))) and (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon)) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near sem)))) and (@ad < "20031017")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 17:36
-	170	(nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 21:51
-	0	(protect\$4 or mask\$4) near2 (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic)) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:28
-	45	(protect\$4 or mask\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic)) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:04
-	39	(dissolv\$4 or etch\$4 or remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic)) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:05
-	0	((protect\$4 or mask\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic)) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon)))) same ((dissolv\$4 or etch\$4 or remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic)) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:05
-	3	((protect\$4 or mask\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic)) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon)))) and ((dissolv\$4 or etch\$4 or remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic)) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:05
-	1952582	semiconductor or silicon or semiconductor\$6	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:15
-	236	(nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconductor\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:15
-	16	met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:17
-	186	(met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:27

-	45	(protect\$4 or mask\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconductor\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:30
-	3	(protect\$4 or mask\$4) near4 (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconductor\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:29
-	3	(selectiv\$4 near2 breakdown\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconductor\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:36
-	3	((protect\$4 or mask\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconductor\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic)))) and ((selectiv\$4 near2 breakdown\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconductor\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic))))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:31
-	0	(selectiv\$4 near2 dissolv\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconductor\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 18:37
-	2	(selectiv\$4 near2 remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (semiconductor or silicon or semiconductor\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntftet or met adj cntftet or met adj swntftet or met adj sntftet) or ((nanotube or nt or cnt or swnt or snt or ntftet or cntftet or swntftet or sntftet) near (metallic or metallic))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 21:54
-	2	6325909.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 19:36
-	1	20040191157.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 19:36
-	0	20040191157.pn. and (substrate or wafer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 19:36

-	1	20040191157.pn. and (silicon or semiconductor)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 19:37
-	1	20040191157.pn. and (silicon or semiconductor\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/30 19:37
-	177	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metallic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 22:58
-	177	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet or swt) near (metallic or metallic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 21:51
-	664	(nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near4 (semiconductor or silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 21:54
-	3	(selectiv\$4 near2 remov\$4) same (((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near2 (semiconductor or silicon or semiconductor\$6)) or ((met adj nanotube or met adj nt or met adj cnt or met adj swnt or met adj snt or met adj ntfet or met adj cntfet or met adj swntfet or met adj sntfet) or ((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metallic))))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 22:21
-	1	20040191157.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 22:21
-	199479	mosfet or (metal adj oxide adj semiconductor adj (fet or field)) or pmos or cmos or nmos or misfet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 22:22
-	0	20040191157.pn. and (mosfet or (metal adj oxide adj semiconductor adj (fet or field)) or pmos or cmos or nmos or misfet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 22:23
-	0	20040191157.pn. and (transistor or fet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 22:23
-	7	((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metallic)) same (current or voltage) same (dissolv\$4 or burn or destroy\$4 or remov\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 23:00
-	7	((nanotube or nt or cnt or swnt or snt or ntfet or cntfet or swntfet or sntfet) near (metallic or metallic)) same (current or voltage) same (dissolv\$4 or burn or destroy\$4 or remov\$4)) and (@ad < "20031017")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/11/05 23:00